

IntelliMAX™ Dual-Input Single-Output Advanced Power Switch with True Reverse-Current Blocking



ON Semiconductor®

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FPF1320, FPF1321

Description

The FPF1320/21 is a Dual-Input Single-Output (DISO) load switch consisting of two sets of slew-rate controlled, low on-resistance, P-channel MOSFET switches and integrated analog features. The slew-rate-controlled turn-on characteristic prevents inrush current and the resulting excessive voltage droop on the power rails. The input voltage range operates from 1.5 V to 5.5 V to align with the requirements of low-voltage portable device power rails. FPF1320/21 performs seamless power-source transitions between two input power rails using the SEL pin with advanced break-before-make operation.

FPF1320/21 has a TRCB function to block unwanted reverse current from output to input during ON/OFF states. The switch is controlled by logic inputs of the SEL and EN pins, which are capable of interfacing directly with low-voltage control signals (GPIO).

FPF1321 has 65 Ω on-chip load resistor for output quick discharge when EN is LOW.

FPF1320/21 is available in 1.0 mm x 1.5 mm WLCSP, 6-bump, with 0.5 mm pitch. FPF1321B is available in 1.0 mm x 1.5 mm WLCSP, 6-bump, 0.5 mm pitch with backside laminate.

Features

- DISO Load Switches
- Input Supply Operating Range: 1.5 V ~ 5.5 V
- R_{ON} 50 mΩ at $V_{IN} = 3.3$ V Per Channel (Typical)
- True Reverse – Current Blocking (TRCB)
- Fixed Slew Rate Controlled 130 μs for < 1 μF C_{OUT}
- I_{SW} : 1.5 A Per Channel (Maximum)
- Quick Discharge Feature on FPF1321
- Logic CMOS IO Meets JESD76 Standard for GPIO Interface and Related Power Supply Requirements
- ESD Protected:
 - ◆ Human Body Model: > 6 kV
 - ◆ Charged Device Model: > 1.5 kV
 - ◆ IEC 61000-4-2 Air Discharge: > 15 kV
 - ◆ IEC 61000-4-2 Contact Discharge: > 8 kV
- These are Pb-Free and Halide Free Devices

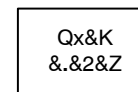
Applications

- Smart Phones / Tablet PCs
- Portable Devices
- Near Field Communication (NFC) Capable SIM Card Power Supply



WLCSP-6
CASE 567RM

MARKING DIAGRAM



Qx	= Specific Device Code x = S or T
&K	= Traceability Code
&.	= Pin one dot
&2	= Date Code
&Z	= Assembly plant code

ORDERING INFORMATION

See detailed ordering and shipping information on page 12 of this data sheet.

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APPLICATION DIAGRAM

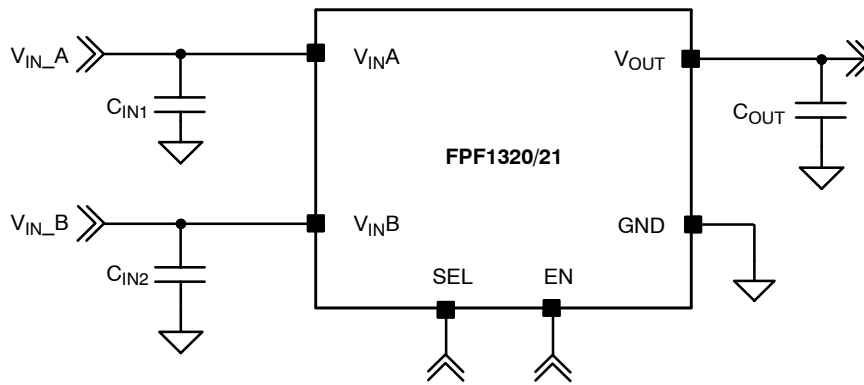


Figure 1. Typical Application

BLOCK DIAGRAM

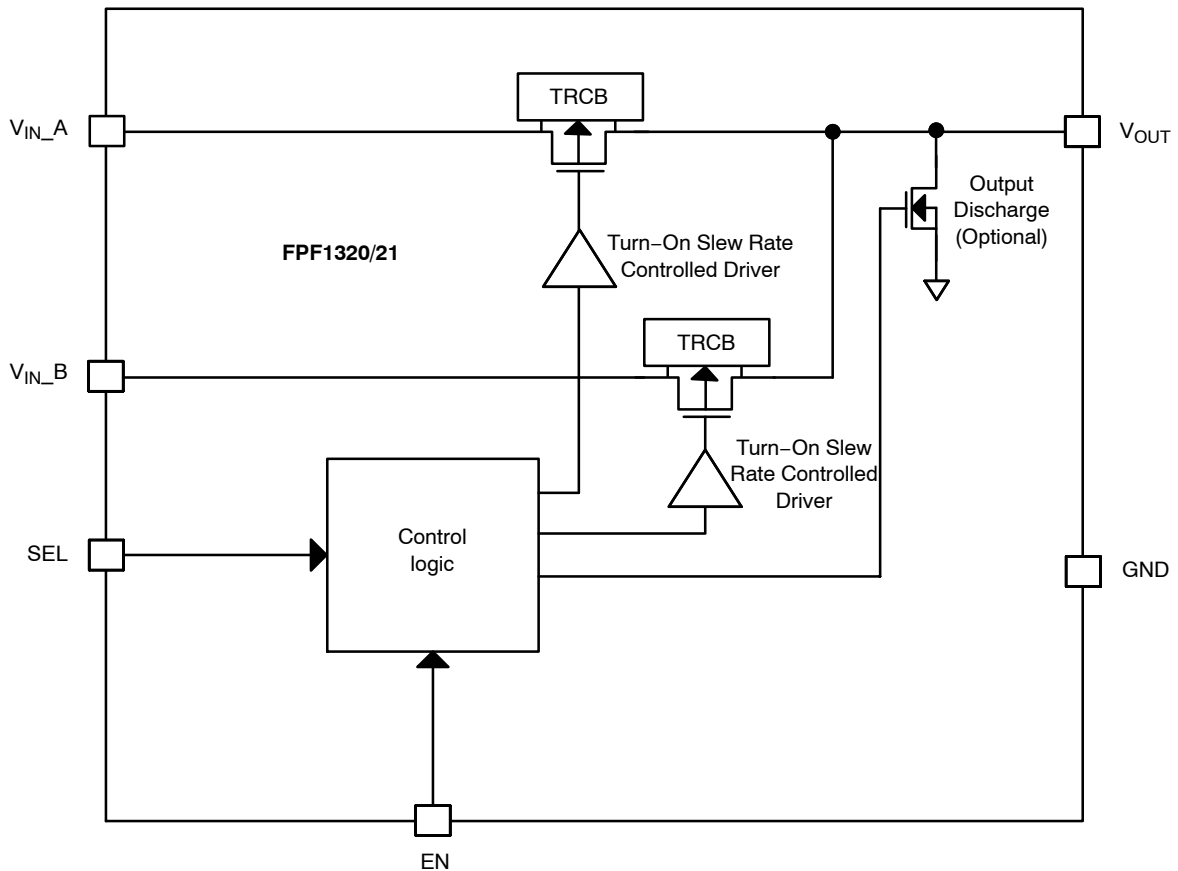


Figure 2. Functional Block Diagram (Output Discharge Path for FPF1321 Only)

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PIN CONFIGURATION

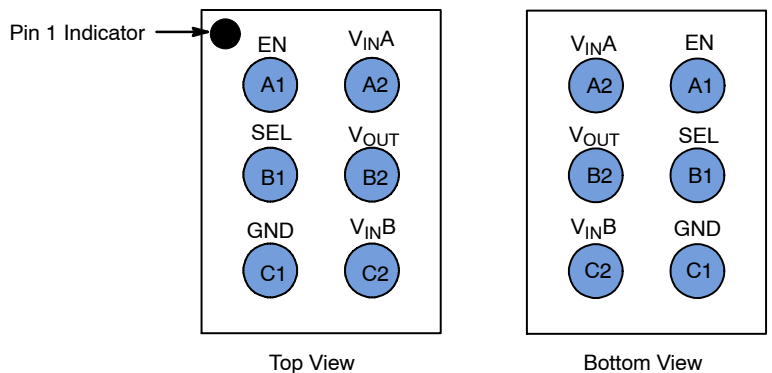


Figure 3. Pin Assignments

PIN DESCRIPTION

Pin #	Name	Description
A1	EN	Enable input. Active HIGH. There is an internal pull-down resistor at the EN pin.
B1	SEL	Input power selection inputs. See Truth Table. There are internal pull-down resistors at the SEL pins.
A2	$V_{IN A}$	Supply Input. Input to the power switch A.
B2	V_{OUT}	Switch output
C1	GND	Ground
C2	$V_{IN B}$	Supply Input. Input to power switch B.

TRUTH TABLE

SEL	EN	Switch A	Switch B	V_{OUT}	Status
Low	High	ON	OFF	$V_{IN A}$	$V_{IN A}$ Selected
High	High	OFF	ON	$V_{IN B}$	$V_{IN B}$ Selected
X	Low	OFF	OFF	Floating for FPF1320 GND for FPF1321	Both Switches are OFF

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ABSOLUTE MAXIMUM RATINGS

Symbol	Parameters	Min	Max	Unit	
V_{IN}	V_{INA} , V_{INB} , V_{SEL} , V_{EN} , V_{OUT} to GND	-0.3	6	V	
I_{SW}	Maximum Continuous Switch Current per Channel	-	1.5	A	
P_D	Total Power Dissipation at $T_A = 25^\circ\text{C}$	-	1.2	W	
T_{STG}	Operating and Storage Junction Temperature	-65	150	$^\circ\text{C}$	
Θ_{JA}	Thermal Resistance, Junction-to-Ambient (1 in. ² Pad of 2-oz. Copper)	-	85 (Note 1)	$^\circ\text{C/W}$	
		-	110 (Note 2)		
ESD	Electrostatic Discharge Capability	Human Body Model, JESD22-A114	6.0	-	kV
		Charged Device Model, JESD22-C101	1.5	-	
		Air Discharge (V_{INA} , V_{INB} to GND), IEC61000-4-2 System Level	15.0	-	
		Contact Discharge (V_{INA} , V_{INB} to GND), IEC61000-4-2 System Level	8.0	-	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Measured using 2S2P JEDEC std. PCB.
2. Measured using 2S2P JEDEC PCB cold-plate method.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameters	Min	Max	Unit
V_{IN}	Input Voltage on V_{INA} , V_{INB}	1.5	5.5	V
T_A	Ambient Operating Temperature	-40	85	$^\circ\text{C}$

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

ELECTRICAL CHARACTERISTICS $V_{INA} = V_{INB} = 1.5$ to 5.5 V, $T_A = -40$ to 85°C unless otherwise noted. Typical values are at $V_{INA} = V_{INB} = 3.3$ V, $T_A = 25^\circ\text{C}$

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
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BASIC OPERATION

V_{INA} , V_{INB}	Input Voltage	-	1.5	-	5.5	V
I_{SD}	Shutdown Current	SEL = HIGH or LOW, EN = GND, $V_{OUT} = \text{GND}$, $V_{INA} = V_{INB} = 5.5$ V	-	-	5	μA
I_Q	Quiescent Current	$I_{OUT} = 0$ mA, SEL = HIGH or LOW, EN = HIGH, $V_{INA} = V_{INB} = 5.5$ V	-	12	22	μA
R_{ON}	On-Resistance	$V_{INA} = V_{INB} = 5.5$ V, $I_{OUT} = 200$ mA, $T_A = 25^\circ\text{C}$	-	42	60	m Ω
		$V_{INA} = V_{INB} = 3.3$ V, $I_{OUT} = 200$ mA, $T_A = 25^\circ\text{C}$	-	50	-	
		$V_{INA} = V_{INB} = 1.8$ V, $I_{OUT} = 200$ mA, $T_A = 25^\circ\text{C}$ to 85°C	-	80	-	
		$V_{INA} = V_{INB} = 1.5$ V, $I_{OUT} = 200$ mA, $T_A = 25^\circ\text{C}$	-	-	170	
V_{IH}	SEL, EN Input Logic High Voltage	V_{INA} , $V_{INB} = 1.5$ V – 5.5 V	1.15	-	-	V
V_{IL}	SEL, EN Input Logic Low Voltage	V_{INA} , $V_{INB} = 1.8$ V – 5.5 V	-	-	0.65	V
	SEL, EN Input Logic Low Voltage	V_{INA} , $V_{INB} = 1.5$ V – 1.8 V	-	-	0.60	
V_{DROOP_OUT}	Output Voltage Droop while Channel Switching from Higher Input Voltage Lower Input Voltage (Note 3)	$V_{INA} = 3.3$ V, $V_{INB} = 5$ V, Switching from $V_{INA} \rightarrow V_{INB}$, $R_L = 150$ Ω , $C_{OUT} = 1$ μF	-	-	100	mV
I_{SEL}/I_{EN}	Input Leakage at SEL and EN Pin	-	-	-	1.2	μA

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ELECTRICAL CHARACTERISTICS $V_{IN A} = V_{IN B} = 1.5$ to 5.5 V, $T_A = -40$ to 85°C unless otherwise noted. Typical values are at $V_{IN A} = V_{IN B} = 3.3$ V, $T_A = 25^\circ\text{C}$ (continued)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
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BASIC OPERATION (continued)

R_{SEL_PD}/R_{EN_PD}	Pull-Down Resistance at SEL or EN Pin	-	-	7	-	M Ω
R_{PD}	Output Pull-Down Resistance	SEL = HIGH or LOW, EN = GND, $I_{FORCE} = 20$ mA, $T_A = 25^\circ\text{C}$, FPF1321	-	65	-	Ω

TRUE REVERSE CURRENT BLOCKING

V_{T_RCB}	RCB Protection Trip Point	$V_{OUT} - V_{IN A}$ or $V_{IN B}$	-	45	-	mV
V_{R_RCB}	RCB Protection Release Trip Point	$V_{IN A}$ or $V_{IN B} - V_{OUT}$	-	25	-	mV
I_{RCB}	$V_{IN A}$ or $V_{IN B}$ Current During RCB	$V_{OUT} = 5.5$ V, $V_{IN A}$ or $V_{IN B} =$ Short to GND	-	9	15	μA
t_{RCB_ON}	RCB Response Time when Device is ON (Note 3)	$V_{IN A}$ or $V_{IN B} = 5$ V, $V_{OUT} V_{IN A, B} = 100$ mV	-	5	-	μs

DYNAMIC CHARACTERISTICS

t_{DON}	Turn-On Delay (Note 4)	$V_{IN A}$ or $V_{IN B} = 3.3$ V, $R_L = 150$ Ω , $C_L = 1$ μF , $T_A = 25^\circ\text{C}$, SEL: HIGH, EN: LOW \rightarrow HIGH	-	120	-	μs
t_R	V_{OUT} Rise Time (Note 4)		-	130	-	
t_{ON}	Turn-On Time (Note 6)		-	250	-	
t_{DOFF}	Turn-Off Delay (Note 4)	$V_{IN A}$ or $V_{IN B} = 3.3$ V, $R_L = 150$ Ω , $C_L = 1$ μF , $T_A = 25^\circ\text{C}$, SEL: HIGH, EN: HIGH \rightarrow LOW	-	15	-	μs
t_F	V_{OUT} Fall Time (Note 4)		-	320	-	
t_{OFF}	Turn-Off Time (Note 7)		-	335	-	
t_{DOFF}	Turn-Off Delay (Note 4, Note 5)	$V_{IN A}$ or $V_{IN B} = 3.3$ V, $R_L = 150$ Ω , $C_L = 1$ μF , $T_A = 25^\circ\text{C}$, SEL: HIGH, EN: HIGH \rightarrow LOW, Output Discharge Mode, FPF1321	-	6	-	μs
t_F	V_{OUT} Fall Time (Note 4, Note 5)		-	110	-	
t_{OFF}	Turn-Off Time (Note 5, Note 7)		-	116	-	
t_{TRANR}	Transition Time LOW \rightarrow HIGH (Note 4)	$V_{IN A} = 3.3$ V, $V_{IN B} = 5$ V, Switching from $V_{IN A} \rightarrow V_{IN B}$, SEL: LOW \rightarrow HIGH, EN: HIGH, $R_L = 150$ Ω , $C_L = 1$ μF , $T_A = 25^\circ\text{C}$	-	3	-	μs
t_{SLH}	Switch-Over Rising Delay (Note 4)		-	1	-	
t_{TRANF}	Transition Time HIGH \rightarrow LOW (Note 4)	$V_{IN A} = 3.3$ V, $V_{IN B} = 5$ V, Switching from $V_{IN B} \rightarrow V_{IN A}$, SEL: HIGH \rightarrow LOW, EN: HIGH, $R_L = 150$ Ω , $C = 1$ μF , $T_A = 25^\circ\text{C}$	-	45	-	μs
t_{SHL}	Switch-Over Falling Delay (Note 4)		-	5	-	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. This parameter is guaranteed by design and characterization; not production tested.

4. $t_{DON}/t_{DOFF}/t_R/t_F/t_{TRANR}/t_{TRANF}/t_{SLH}/t_{SHL}$ are defined in Figure 4.

5. FPF1321 output discharge is enabled during off.

6. $t_{ON} = t_R + t_{DON}$

7. $t_{OFF} = t_F + t_{DOFF}$

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TIMING DIAGRAM

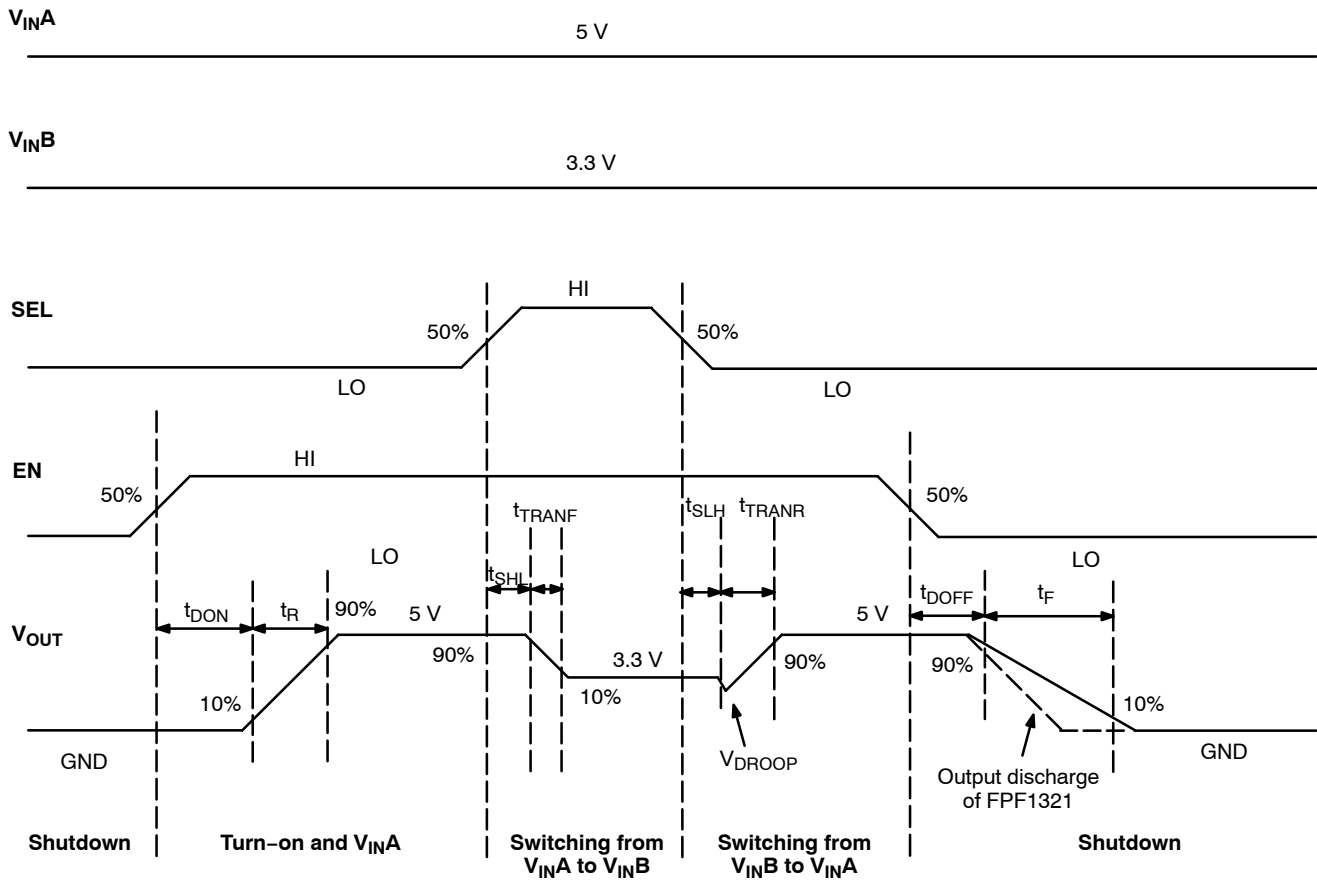


Figure 4. Dynamic Behavior Timing Diagram

TYPICAL CHARACTERISTICS

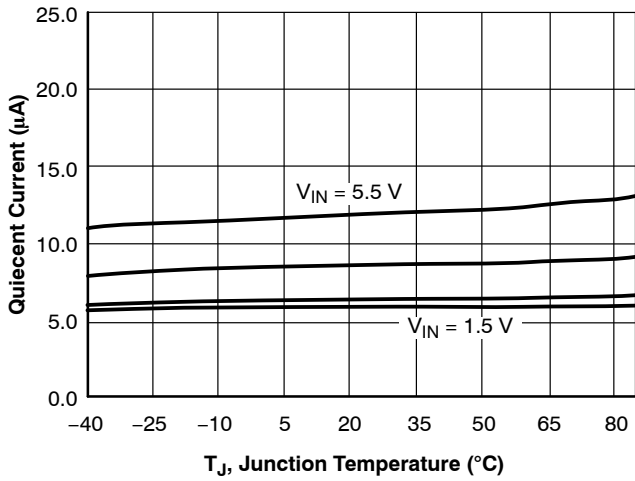


Figure 5. Supply Current vs. Temperature

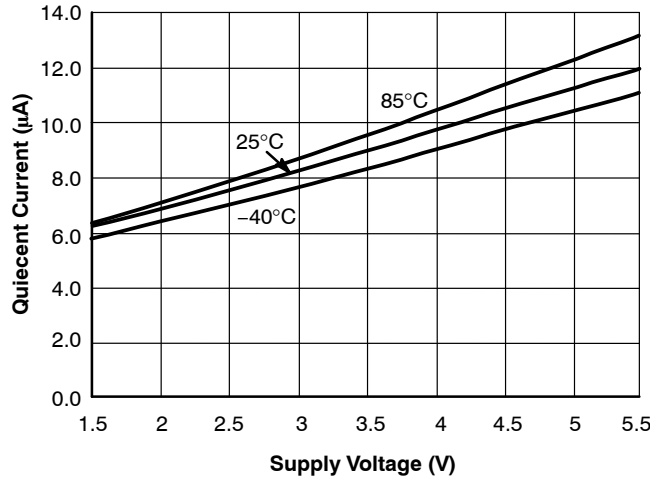


Figure 6. Supply Current vs. Supply Voltage

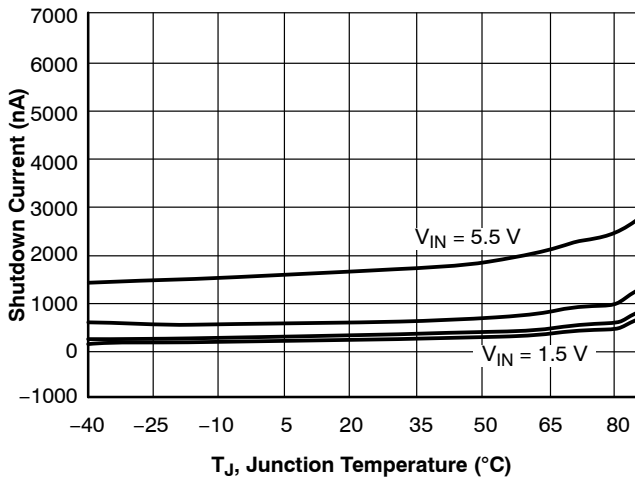


Figure 7. Shutdown Current vs. Temperature

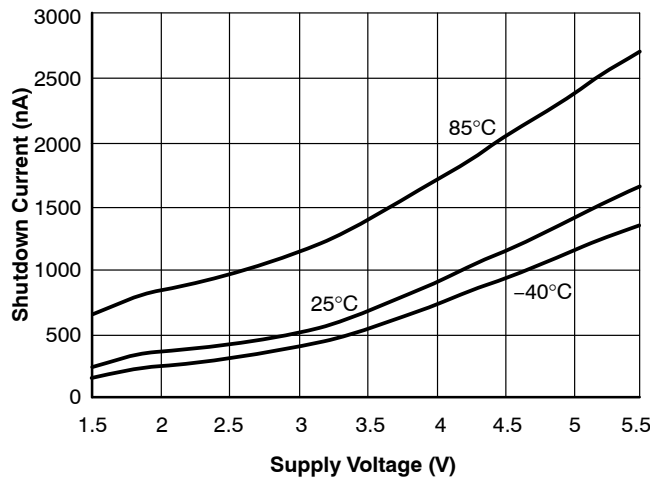


Figure 8. Shutdown Current vs. Supply Voltage

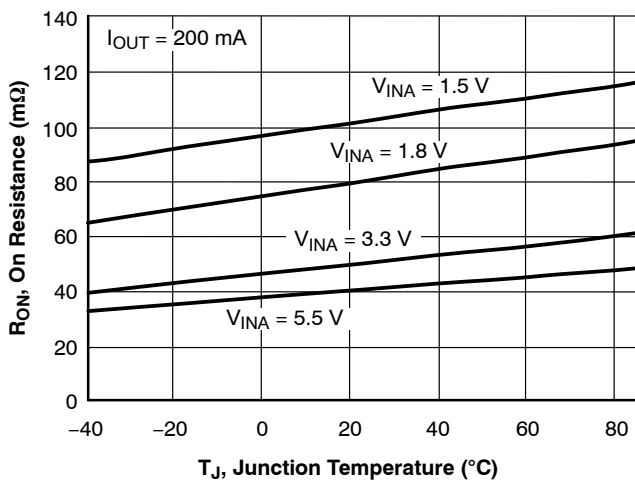


Figure 9. RON vs. Temperature

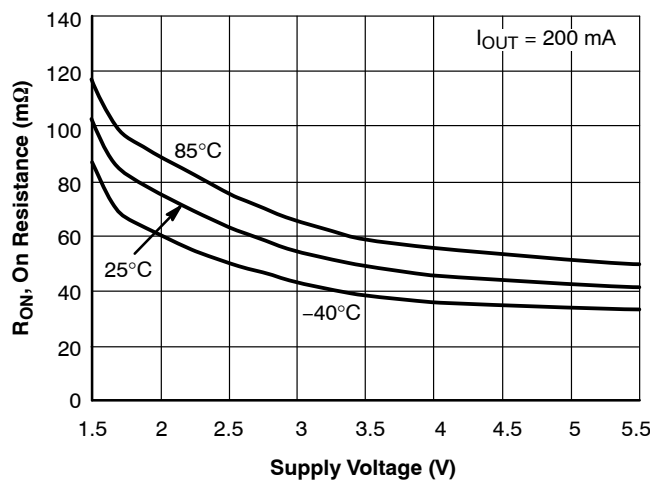


Figure 10. RON vs. Supply Voltage

TYPICAL CHARACTERISTICS (continued)

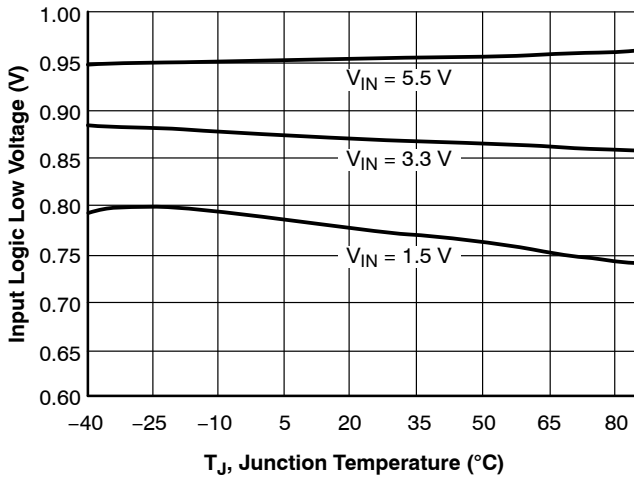


Figure 11. V_{IL} vs. Temperature

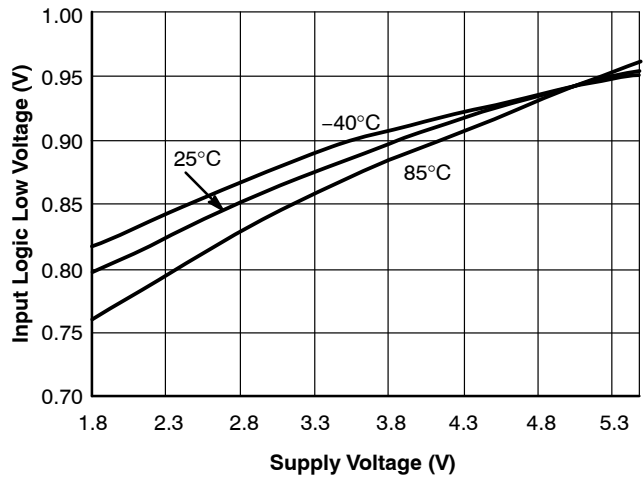


Figure 12. V_{IL} vs. Supply Voltage

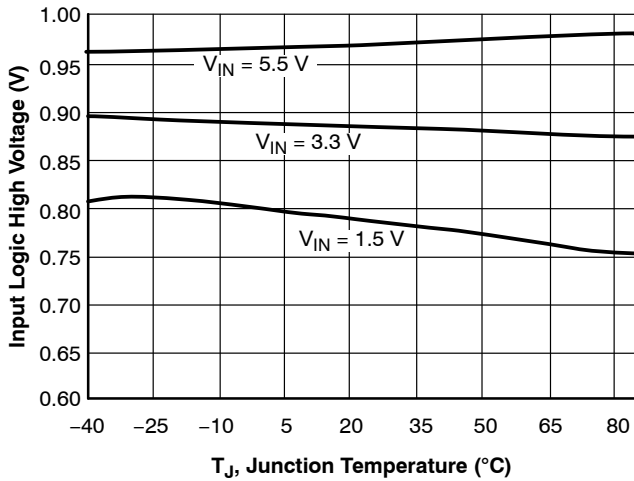


Figure 13. V_{IH} vs. Temperature

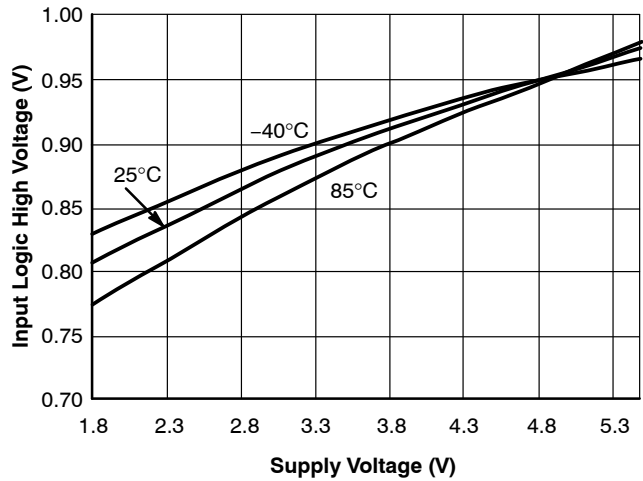


Figure 14. V_{IH} vs. Supply Voltage

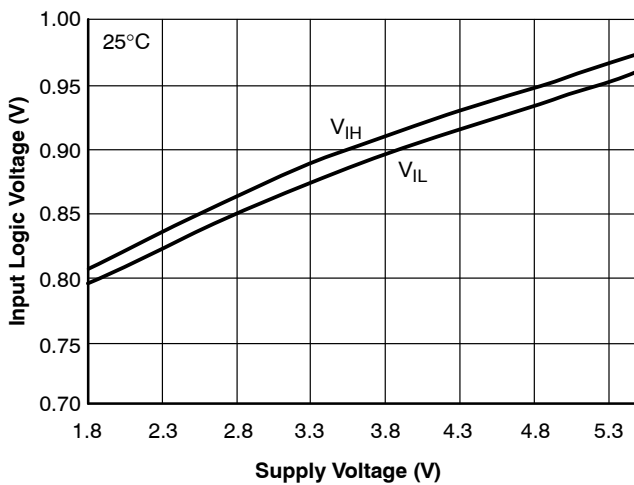


Figure 15. V_{IH}/V_{IL} vs. Supply Voltage

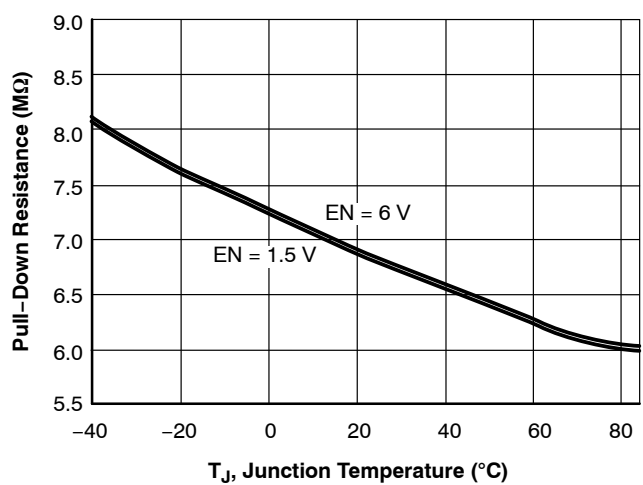


Figure 16. R_{SEL_PD} and R_{EN_PD} vs. Temperature

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TYPICAL CHARACTERISTICS (continued)

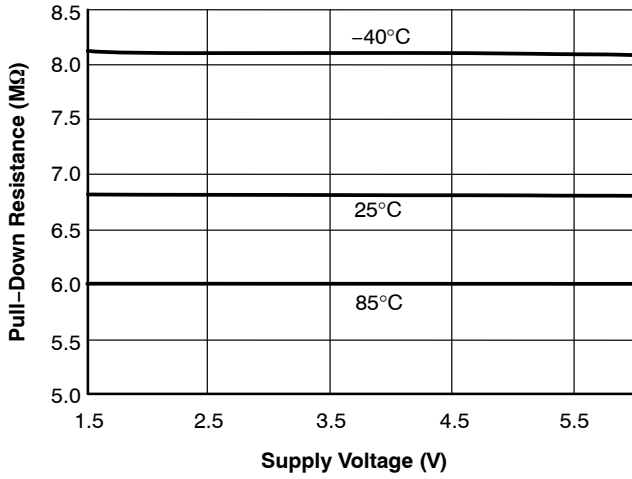


Figure 17. R_{SEL_PD} and R_{EN_PD} vs. Supply Voltage

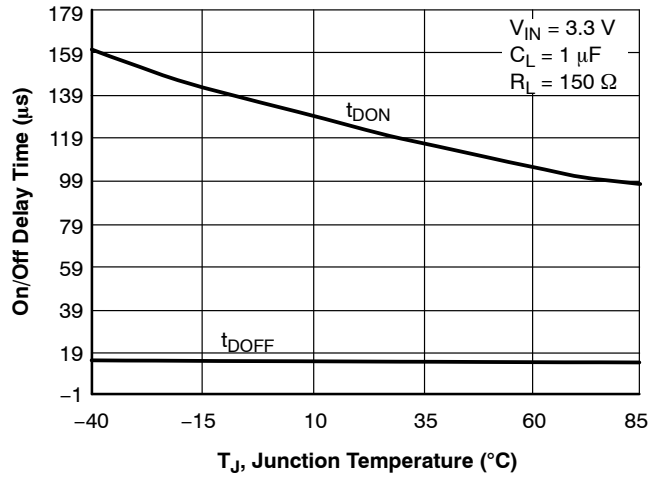


Figure 18. t_{DON} and t_{DOFF} vs. Temperature

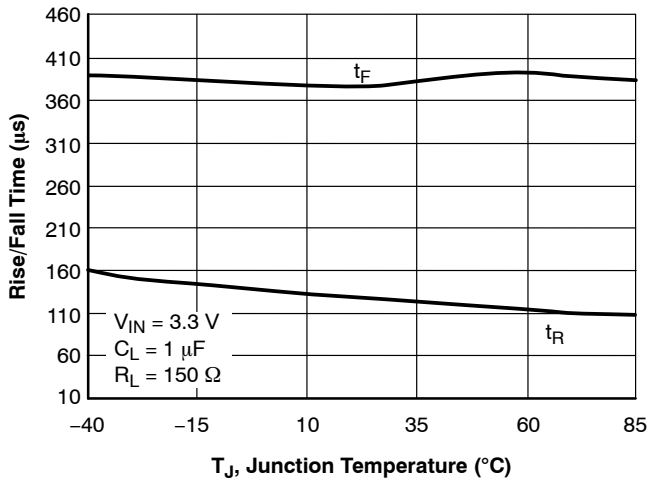


Figure 19. t_R and t_F with FPF1320 vs. Temperature

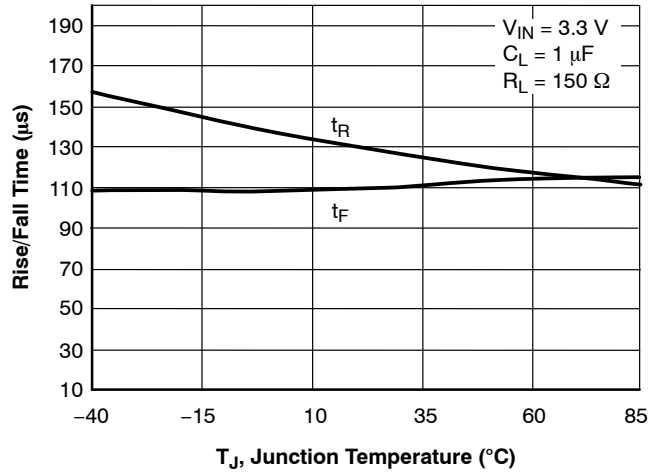


Figure 20. t_R and t_F with FPF1321 vs. Temperature

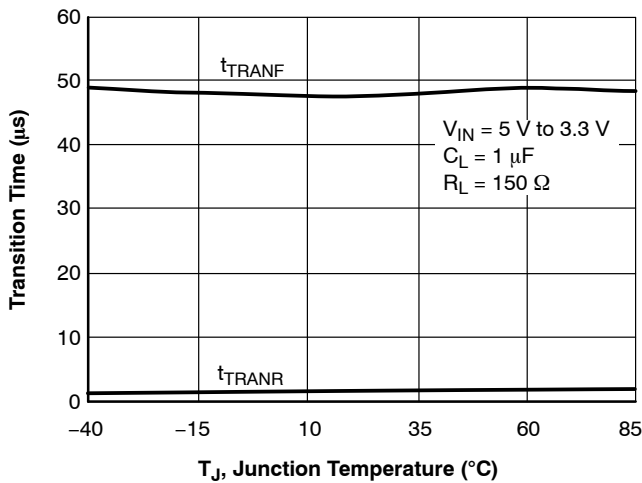


Figure 21. Transition Time vs. Temperature

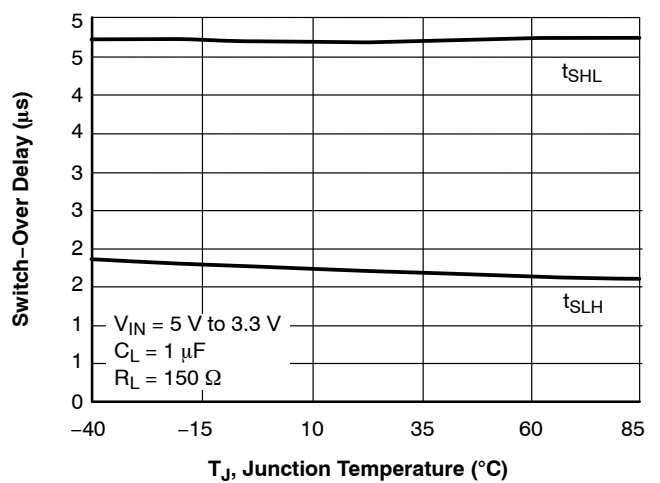


Figure 22. Switch Over Time vs. Temperature

TYPICAL CHARACTERISTICS (continued)

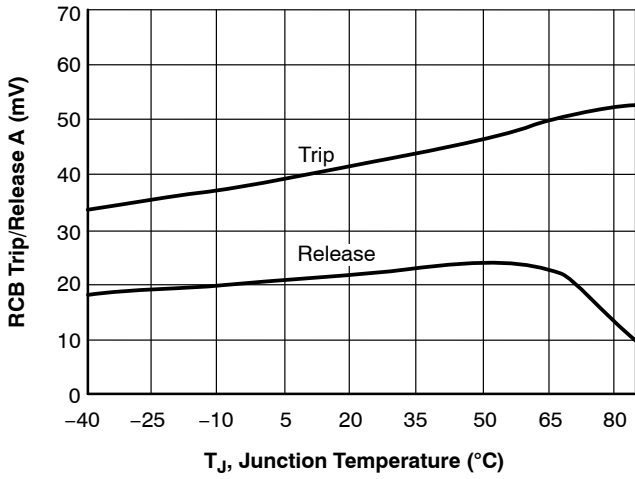


Figure 23. TRCB Trip and Release vs. Temperature

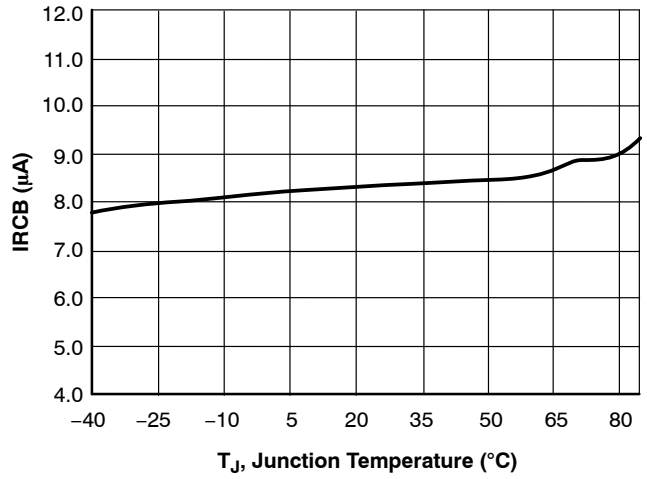


Figure 24. Ircb vs. Temperature

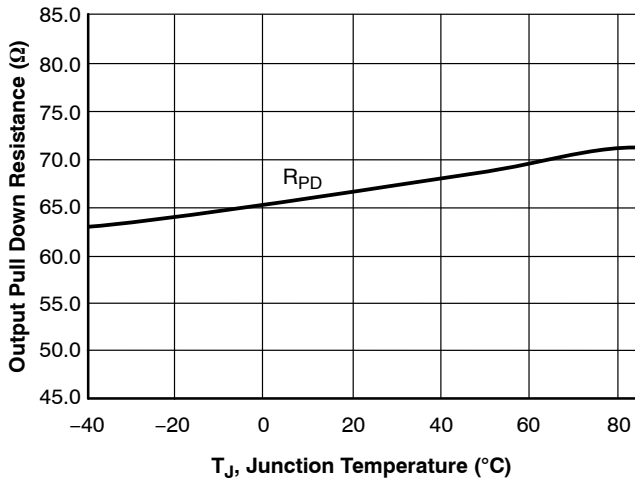


Figure 25. Rpd with FPF1321 vs. Temperature

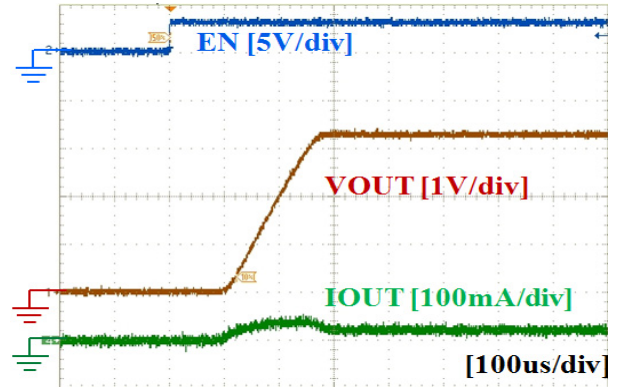


Figure 26. Turn-On Response
($V_{IN} = 3.3\text{ V}$, $C_{IN} = 1\ \mu\text{F}$, $C_{OUT} = 1\ \mu\text{F}$, $R_L = 150\ \Omega$,
SEL = LOW)

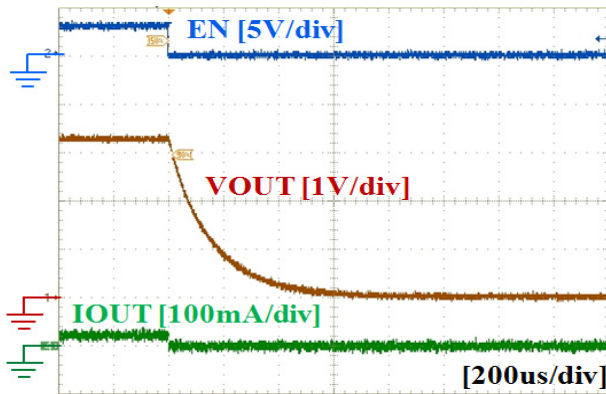


Figure 27. Turn-Off Response with FPF1320
($V_{IN} = 3.3\text{ V}$, $C_{IN} = 1\ \mu\text{F}$, $C_{OUT} = 1\ \mu\text{F}$, $R_L = 150\ \Omega$,
SEL = LOW)

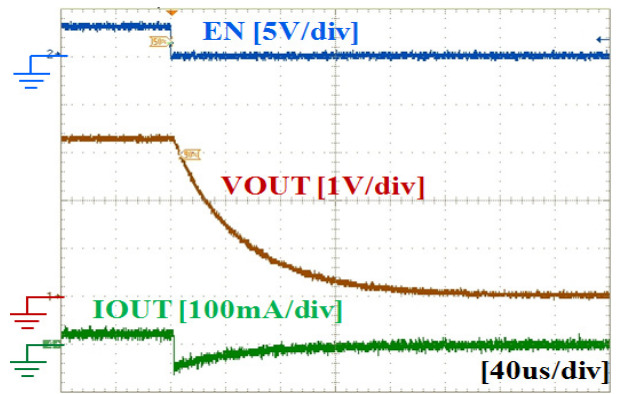


Figure 28. Turn-Off Response with FPF1321
($V_{IN} = 3.3\text{ V}$, $C_{IN} = 1\ \mu\text{F}$, $C_{OUT} = 1\ \mu\text{F}$, $R_L = 150\ \Omega$,
SEL = LOW)

TYPICAL CHARACTERISTICS (continued)

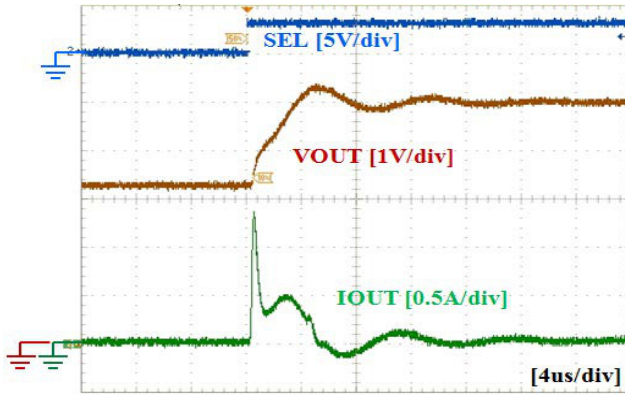


Figure 29. Power Source Transition from 3.3 V to 5 V ($V_{IN A} = 3.3$ V, $V_{IN B} = 5$ V, $C_{IN} = 1$ μ F, $C_{OUT} = 1$ μ F, $R_L = 150$ Ω)

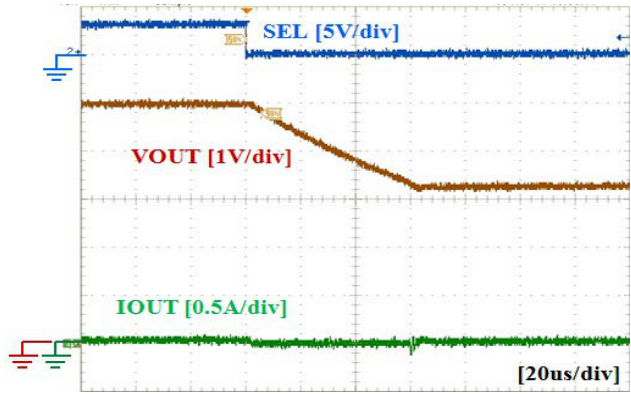


Figure 30. Power Source Transition from 5 V to 3.3 V ($V_{IN A} = 3.3$ V, $V_{IN B} = 5$ V, $C_{IN} = 1$ μ F, $C_{OUT} = 1$ μ F, $R_L = 150$ Ω)

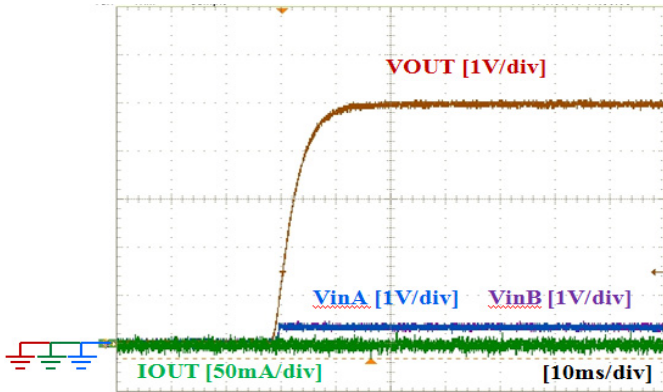


Figure 31. TRCB During Off ($V_{IN A} = V_{IN B} =$ Floating, $V_{OUT} = 5$ V, $C_{IN} = 1$ μ F, $C_{OUT} = 1$ μ F, EN = LOW, No R_L)

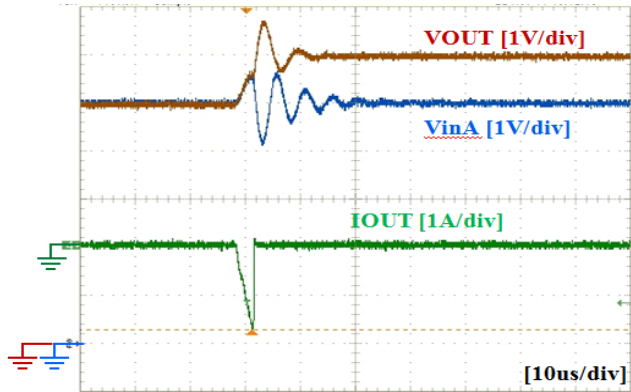


Figure 32. TRCB During On ($V_{IN A} = 5$ V, $V_{OUT} = 6$ V, $C_{IN} = 1$ μ F, $C_{OUT} = 1$ μ F, EN = HIGH, No R_L)

OPERATION AND APPLICATION DESCRIPTION

The FPF1320 and FPF1321 are dual-input single-output power multiplexer switches with controlled turn-on and seamless power source transition. The core is a 50 m Ω P-channel MOSFET and controller capable of functioning over a wide input operating range of 1.5 V to 5.5 V per channel. The EN and SEL pins are active-HIGH, GPIO/CMOS-compatible input. They control the state of the switch and input power source selection, respectively. TRCB functionality blocks unwanted reverse current during both ON and OFF states when higher V_{OUT} than $V_{IN A}$ or $V_{IN B}$ is applied. FPF1321 has a 65 Ω output discharge path during off.

Input Capacitor

To limit the voltage drop on the input supply caused by transient inrush current when the switch turns on into a discharged load capacitor; a capacitor must be placed between the $V_{IN A}$ or $V_{IN B}$ pins to the GND pin. At least 1 μ F ceramic capacitor, C_{IN} , placed close to the pins, is usually sufficient. Higher-value C_{IN} can be used to reduce more the voltage drop.

Inrush Current

Inrush current occurs when the device is turned on. Inrush current is dependent on output capacitance and slew rate control capability, as expressed by:

$$I_{INRUSH} = C_{OUT} \times \frac{V_{IN} - V_{INITIAL}}{t_R} + I_{LOAD} \quad (\text{eq. 1})$$

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where:

C_{OUT} : Output capacitance;
 t_R : Slew rate or rise time at V_{OUT} ;
 V_{IN} : Input voltage, V_{INA} or V_{INB} ;
 $V_{INITIAL}$: Initial voltage at C_{OUT} , usually GND; and
 I_{LOAD} : Load current.

Higher inrush current causes higher input voltage drop, depending on the distributed input resistance and input capacitance. High inrush current can cause problems.

FPF1320/1 has a 130 μ s of slew rate capability under 3.3 V_{IN} at 1 μ F of C_{OUT} and 150 Ω of R_L so inrush current and input voltage drop can be minimized.

Power Source Selection

Input power source selection can be controlled by the SEL pin. When SEL is LOW, output is powered from V_{INA} while SEL is HIGH, V_{INB} is powering output. The SEL signal is ignored during device OFF.

Output Voltage Drop During Transition

Output voltage drop usually occurs during input power source transition period from low voltage to high voltage. The drop is highly dependent on output capacitance and load current.

FPF1320/1 adopts an advanced break-before-make control, which can result in minimized output voltage drop during the transition time.

Output Capacitor

Capacitor C_{OUT} of at least 1 μ F is highly recommended between the V_{OUT} and GND pins to achieve minimized output voltage drop during input power source transition. This capacitor also prevents parasitic board inductance.

True Reverse-Current Blocking

The true reverse-current blocking feature protects the input source against current flow from output to input regardless of whether the load switch is on or off.

Board Layout

For best performance, all traces should be as short as possible. To be most effective, the input and output capacitors should be placed close to the device to minimize the effect that parasitic trace inductance on normal and short-circuit operation. Wide traces or large copper planes for power pins (V_{INA} , V_{INB} , V_{OUT} and GND) minimize the parasitic electrical effects and the thermal impedance.

ORDERING INFORMATION

Part Number	Top Mark	Channel	Switch Per Channel (Typ.) at 3.3 V_{IN}	Reverse Current Blocking	Output Discharge	Rise Time (t_R)	Package
FPF1320UCX	QS	DISO	50 m Ω	Yes	NA	130 μ s	1.0 mm \times 1.5 mm Wafer-Level Chip-Scale Package (WLCSP) 6-Bumps, 0.5 mm Pitch
FPF1321UCX	QT	DISO	50 m Ω	Yes	65 Ω	130 μ s	
FPF1321BUCX	QT	DISO	50 m Ω	Yes	65 Ω	130 μ s	

PRODUCT-SPECIFIC DIMENSIONS

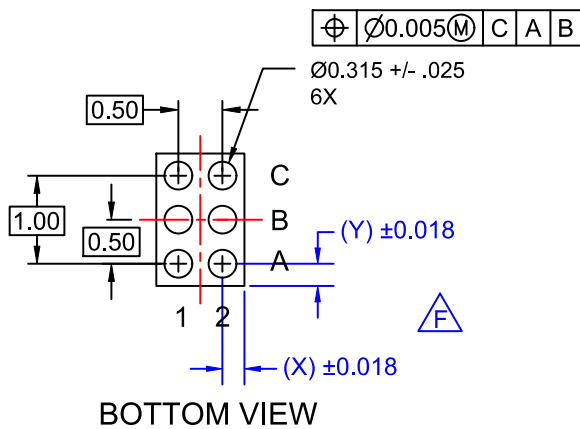
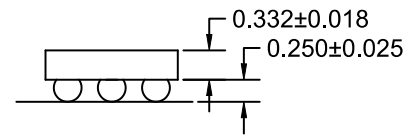
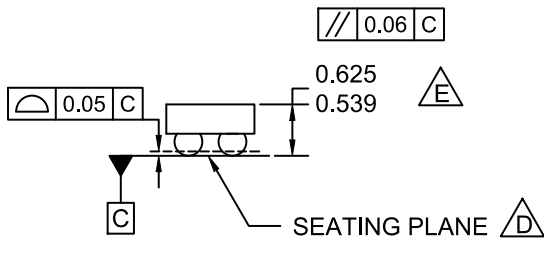
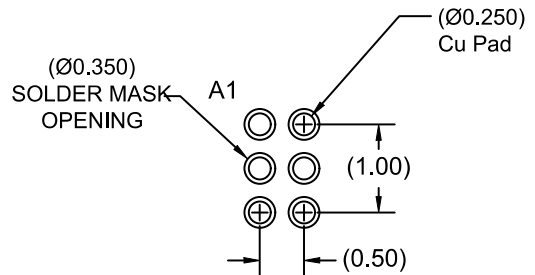
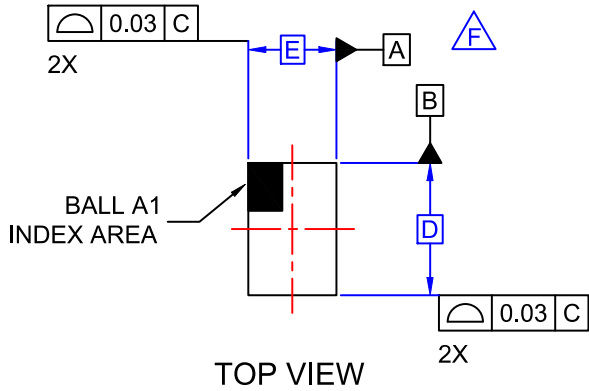
Product	D	E	X	Y
FPF1320UCX	1460 μ m \pm 30 μ m	960 μ m \pm 30 μ m	230 μ m	230 μ m
FPF1321UCX	1460 μ m \pm 30 μ m	960 μ m \pm 30 μ m	230 μ m	230 μ m
FPF1321BUCX	1460 μ m \pm 30 μ m	960 μ m \pm 30 μ m	230 μ m	230 μ m

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WLCSP6 1.46x0.96x0.582
CASE 567RM
ISSUE O

DATE 30 NOV 2016



NOTES:

- A. NO JEDEC REGISTRATION APPLIES.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCE PER ASMEY14.5M, 1994.
- △** DATUM C IS DEFINED BY THE SPHERICAL CROWNS OF THE BALLS.
- △** PACKAGE NOMINAL HEIGHT IS 582 MICRONS ±43 MICRONS (539-625 MICRONS).
- △** FOR DIMENSIONS D, E, X, AND Y SEE PRODUCT DATASHEET.

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